

Kondo effect and spin-active scattering in ferromagnet-superconductor junctionsH. Soller,¹ L. Hofstetter,² S. Csonka,³ A. Levy Yeyati,⁴ C. Schönenberger,² and A. Komnik¹¹*Institut für Theoretische Physik, Ruprecht-Karls-Universität Heidelberg, Philosophenweg 19, D-69120 Heidelberg, Germany*²*Department of Physics, University of Basel, Klingelbergstrasse 82, CH-4056 Basel, Switzerland*³*Department of Physics, Budapest University of Technology and Economics, Budafoki út 6, 1111 Budapest, Hungary*⁴*Departamento de Física Teórica de la Materia Condensada C-V, Universidad Autónoma de Madrid, E-28049 Madrid, Spain*

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We study the interplay of superconducting and ferromagnetic correlations on charge transport in different geometries with a focus on both a quantum point contact as well as a quantum dot in the even and the odd state with and without spin-active scattering at the interface. In order to obtain a complete picture of the charge transport we calculate the full counting statistics in all cases and compare the results with experimental data. We show that spin-active scattering is an essential ingredient in the description of quantum point contacts. This holds also for quantum dots in an even charge state, whereas it is strongly suppressed in a typical Kondo situation. We explain this feature by the strong asymmetry of the hybridizations with the quantum dot and show how Kondo peak splitting in a magnetic field can be used for spin filtering. For the quantum dot in the even state, spin-active scattering allows for an explanation of the experimentally observed mini-gap feature.

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I. INTRODUCTION

The quickly evolving field of spintronics has pointed to an increasing need for a complete understanding of contacts between superconductors (SCs) and spin-polarized materials such as ferromagnets (FMs). Compared to hybrids between a normal metal and a SC, one observes not only the interplay of the two densities of states (DOS) but also effects of the different spin ordering in the contacted materials. Examples of interesting transport effects include probing the spin polarization by use of Andreev reflection,¹⁻⁵ the π junction behavior in Josephson junctions with FM interlayers,⁶⁻⁹ ferromagnetically induced triplet superconductivity,¹⁰⁻¹⁴ and the interplay of these triplet pairs with magnons.^{15,16}

Recent interest was triggered by the observation that spin-active scattering plays an important role in SC FM interfaces¹⁷ and the experimental realization of a ferromagnet-quantum-dot-superconductor (F-QD-S) junction¹⁸ which allows study of the influence and interplay of ferromagnetic and superconducting correlations on transport^{19,20} in the Kondo regime.²¹

So far, theoretical considerations of SC FM hybrids, on the one hand, have mainly concentrated on the I-V characteristics²²⁻²⁵ and noise properties^{26,27} of quantum point contacts. On the other hand, for quantum dot (QD) geometries, only the spin-dependent DOS of the FM and not the additional interface properties have been considered.^{28,29} We show how to access the full counting statistics (FCS) for these structures, including their interface properties to allow for a direct calculation of all statistical moments of the current flow.^{30,31} This allows for a calculation of noise and higher-order cumulants that can be experimentally observed.^{32,33}

In this paper we investigate the FCS of SC FM quantum point contacts (QPCs) in the presence of spin-active scattering and F-QD-S junctions in odd and even charge states. In the latter system we have to keep track of the exchange field related peak splitting of the Kondo resonance.³⁴⁻³⁷ For a QD in an even charge state we show how spin-flip Andreev reflection in combination with the exchange field leads to a new characteristic subgap phenomenon.

The paper is organized as follows: Section II deals with a SC FM quantum point contact without a specific consideration of the interface properties. We find in Sec. III that a consistent interpretation of conductance spectra is possible only by considering spin-active scattering at the interface. In Sec. IV we derive an effective model for a F-QD-S device in the Kondo limit and explain why spin-active scattering does not need to be considered. The effective model allows us to demonstrate how to use the device for spin filtering in Sec. V. To obtain a complete picture of the transport properties of F-QD-S devices we also consider the even state of the QD in Sec. VI and show how spin-active scattering leads to a new subgap structure. We also explain the evolution of the subgap structure in a magnetic field.

II. FERROMAGNET-SUPERCONDUCTOR QUANTUM POINT CONTACT

As a first test system we study a QPC between a SC and a FM (SFQPC). So far, the FCS of this specific arrangement have not been considered explicitly, but they very much resemble the one for the normal-superconductor QPCs³⁸⁻⁴⁰ since the only difference is the spin-dependent DOS. The Hamiltonian of the system reads

$$H = H_f + H_T + H_s, \quad (1)$$

where H_f describes the FM lead using electron field operators $\Psi_{kf\sigma}$ in the Stoner model with an exchange energy h_{ex} as in Ref. 41

$$H_f = \sum_{k,\sigma} \epsilon_k \Psi_{kf\sigma}^+ \Psi_{kf\sigma} - h_{ex} \sum_k (\Psi_{kf\uparrow}^+ \Psi_{kf\uparrow} - \Psi_{kf\downarrow}^+ \Psi_{kf\downarrow}). \quad (2)$$

For simplicity, we set $\hbar = e = k_B = 1$. The FM has a fermionic flat band DOS with asymmetry for the spin- \uparrow and spin- \downarrow tunneling electrons $\rho_{f\sigma} = \rho_f(1 + \sigma P)$, where P is the polarization. The superconducting lead is described by the typical BCS Hamiltonian⁴² in the language of electron field

operators $\Psi_{ks\sigma}$ with its characteristic energy gap Δ_0

$$H_s = \sum_{k,\sigma} \epsilon_k \Psi_{ks\sigma}^+ \Psi_{ks\sigma} + \Delta_0 \sum_k (\Psi_{ks\uparrow}^+ \Psi_{-ks\downarrow}^+ + \Psi_{-ks\downarrow} \Psi_{ks\uparrow}), \quad (3)$$

leading to the energy-dependent DOS $\rho_s = \rho_{0s} |\omega| / \sqrt{\omega^2 - \Delta_0^2}$.

As in previous treatments of similar problems,⁴³ we define the voltage with respect to the chemical potential of the superconducting lead $\mu_s = 0$ so that $V = -\mu_f$, where μ_f is the chemical potential of the FM. The Fermi distribution of the SC is abbreviated by n_s , whereas n_{f+} and $n_{f-} = 1 - n_{f+}(-\omega)$ refer to the electron- and holelike Fermi distributions in the FM, respectively.

The local tunneling Hamiltonian, which is responsible for transfer of electrons between the leads, is given by⁴⁴

$$H_T = \sum_{\sigma} \gamma [\Psi_{s\sigma}^+(x=0) \Psi_{f\sigma}(x=0) + \text{H.c.}], \quad (4)$$

where γ is the amplitude of the tunneling coupling.

To study the FCS we calculate the cumulant generating function (CGF) $\ln \chi(\lambda) = \sum_{n=1}^{\infty} \frac{(i\lambda)^n}{n!} \langle q^n \rangle$ defined as the func-

tional generating the irreducible moments $\langle q^n \rangle$ of the charge (q) distribution by differentiation with respect to the counting field λ . According to Refs. 45–47 the connection to the former Hamiltonian is given by

$$\chi_{\text{SF}}(\lambda) = \left\langle T_C \exp \left[-i \int_C T^{\lambda(t)} dt \right] \right\rangle, \quad (5)$$

where $T^{\lambda(t)}$ denotes H_T after the substitution $\Psi_{f\sigma}(x=0) \rightarrow \Psi_{f\sigma}(x=0) e^{-i\lambda(t)/2}$. C is the Keldysh contour and T_C denotes time ordering on it. The counting field changes sign on the branches of the contour to account for a virtual (or passive) measurement of the charge being transferred⁴⁸ and $\lambda(t)$ is nonzero only during the very long measuring time τ . The different cumulants of the distribution can be obtained via differentiation of the CGF at $\lambda = 0$. The method is by now well established and has been applied to numerous quantum impurity problems (see, e.g., Refs. 49–53). Since the lead degrees of freedom appear quadratically in the total Hamiltonian we can calculate the CGF exactly using the Hamiltonian approach⁵⁴

$$\begin{aligned} \ln \chi_{\text{SF}}(\lambda) = \tau \int \frac{d\omega}{2\pi} \left(\sum_{\sigma} \ln \left\{ \prod_{\alpha=\pm} \{1 + T_{e\alpha\sigma} A_{\alpha}(\omega, \lambda)\} + T_{A2}(2n_s - 1) \{ (2n_s - 1) [(e^{i\lambda} - 1)^2 n_{f-} (1 - n_{f+}) \right. \right. \\ - 2(e^{i\lambda} - 1)(e^{-i\lambda} - 1) n_{f-} n_{f+} + (e^{-i\lambda} - 1)^2 n_{f+} (1 - n_{f-})] + 2n_s (e^{i\lambda} - 1)(e^{-i\lambda} - 1) (n_{1+} - 1 + n_{1-}) \} \\ + T_{\text{BC}} \{ (2n_s - 1)^2 (e^{i\lambda} - e^{-i\lambda})^2 [n_{f-} e^{i\lambda} + n_{f+} e^{-i\lambda} + \beta_1 (1 - \sigma P) n_s (1 - n_s) (e^{i\lambda} - e^{-i\lambda})^2] \\ + n_s (2n_s - 1) \{ 4(n_s - 1) (n_{f+} - 1 + n_{f-}) (e^{i\lambda} - 1 - e^{-i\lambda})^2 + \sigma P \{ 8[(e^{i\lambda} - 1)^2 n_{f+} - (e^{-i\lambda} - 1)^2 n_{f-}] \\ - (e^{-i\lambda} - 1)^3 [e^{3i\lambda} (2n_s - 1) (1 + n_{f-} - n_{f+}) - (2n_s - 1) (n_{f-} - n_{f+} - 1) + e^{2i\lambda} (2n_s (3 + n_{f+} - n_{f-}) \\ - 3 + 7n_{f+}) - e^{i\lambda} (3 + n_{f+} + 2n_s (n_{f+} - 3 - n_{f-}) + 7n_{f-})] \} \} \} \theta \left(\frac{|\omega| - \Delta_0}{\Delta_0} \right) \\ \left. \left. + \ln \{ 1 + T_A [n_{f+} (1 - n_{f-}) (e^{2i\lambda} - 1) + n_{f-} (1 - n_{f+}) (e^{-2i\lambda} - 1)] \} \theta \left(\frac{\Delta_0 - |\omega|}{\Delta_0} \right) \right\} \right), \quad (6) \end{aligned}$$

involving the abbreviation $A_{\alpha}(\omega, \lambda) = [n_{f\alpha} (1 - n_s) (e^{i\alpha\lambda} - 1) + n_s (1 - n_{f\alpha}) (e^{-i\alpha\lambda} - 1)]$ and the effective transmission coefficients

$$\begin{aligned} T_{e\sigma}(\omega) &= \frac{4\beta_1(1 + \sigma P)}{[1 + \beta_1(1 + \sigma P)]^2 - \beta_2^2(1 - P)(1 + P)}, \\ T_{A2}(\omega) &= \frac{4\beta_A^2(1 + P)(1 - P)}{\{ [1 + \beta_1(1 + P)]^2 - \beta_2^2(1 - P)(1 + P) \} \{ [1 + \beta_1(1 - P)]^2 - \beta_2^2(1 - P)(1 + P) \}} = \frac{T_{\text{BC}}}{\beta_1} \end{aligned}$$

and

$$T_A(\omega) = \frac{4\beta_2^2(1 + P)(1 - P)}{\beta_2^4(1 - P^2)^2 + \beta_2^2(1 - P^2)[2 - \beta_1^2(1 + P)^2 - \beta_1^2(1 - P^2)] + [1 + \beta_1^2(1 + P^2)][1 + \beta_1^2(1 - P^2)]}. \quad (7)$$

The SC DOS enters via the transparencies $\beta_1 = \beta_n |\omega| / \sqrt{|\omega^2 - \Delta_0^2|}$ and $\beta_2 = \beta_n \Delta_0 / \sqrt{|\Delta_0^2 - \omega^2|}$ with $\beta_n = \pi^2 \rho_f \rho_s \gamma^2 / 2$ being the tunneling rate between the contacts. The expression is valid at arbitrary temperatures taking the temperature dependence of Δ_0 into account. The difference

compared to normal-superconductor QPCs (NSQPCs) is the appearance of the polarization P . Consequently, the result for the CGF for NSQPCs obtained in Ref. 39 can easily be recovered by choosing $P = 0$. The transmission coefficients $T_{e\sigma}$ refer to single electron transfer, while T_{A2} and T_{BC} describe the additional contributions from Andreev reflection above

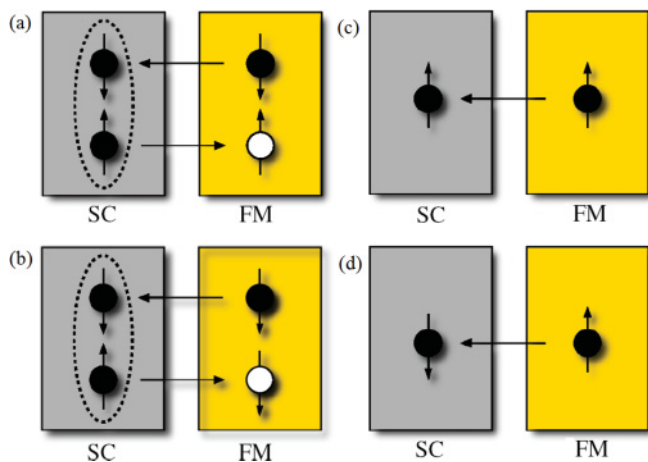


FIG. 1. (Color online) Different transport processes in a SFQPC with spin-active scattering. (a) shows the typical Andreev reflection and (c) displays the typical single electron transmission between a SC and a FM. In (b) we show the SAR process involving a spin flip at the interface and giving rise to triplet correlations in the FM. Likewise also spin-flip transmissions occur as indicated in (d).

the gap and branch crossing, respectively. The transmission coefficient for Andreev reflection processes below the gap is denoted by T_A .

The CGF demonstrates that, also in the case of SFQPCs, the elementary processes of charge transfer can be identified as normal electron transfer between the electrodes above the gap and Andreev reflection processes⁵⁵ below the gap; see Figs. 1(c) and 1(a). Andreev reflection here refers to the charge transfer via an electron that is transmitted from the FM to the SC and is retroreflected as a hole.

However, if we compare the results we obtain for the differential conductance to the experimental results for Al/Cu contacts with good transparencies¹ we need to introduce a sizable broadening of the BCS DOS described by a Dynes parameter Γ_D that has to be of the order $\Gamma_D = 0.21\Delta_0$ to obtain quantitative agreement.^{56,57} Such a distortion is unexpected since the Al/Cu contacts fabricated by the same experimental procedure do not show any distorted BCS DOS.

This is not a problem of the Hamiltonian approach but has also been encountered when fitting I-V spectra to an extension⁵⁸ of the Blonder-Tinkham-Klapwijk (BTK) model.^{24,59} Instead of a Dynes parameter one could introduce an effective temperature⁶⁰ but a reliable explanation of the spectra under debate^{4,61,62} may be obtained only by changing the model of the interface region.²²

III. FERROMAGNET-SUPERCONDUCTOR QUANTUM POINT CONTACT WITH SPIN-ACTIVE SCATTERING

In the previous Section it is mentioned that a realistic description of the interface region is necessary for a complete understanding of SFQPCs. This can be achieved by considering a more complex model that explicitly includes a spin-dependent scattering potential^{22,63} at the interface. This is of special importance when dealing with the experimentally relevant case of strong spin polarization $P \approx 0.2-0.8$. The mechanism of spin-active scattering at the interface is the

interplay of the ferromagnetic exchange field in both the bulk and the interface. In the simplest case, the two magnetic moments deep in the bulk and at the interface would just be parallel. However, manifold processes may lead to an interface magnetic moment differing from the bulk, such as using a thin magnetic layer, spin-orbit coupling, magnetic anisotropy, or spin relaxation. So far, the study of the I-V characteristics of point contact spectra have been performed using a quasiclassical Green's function approach^{22,64} or a wave-function matching technique.⁶⁵ Moreover, noise properties have been analyzed using a scattering states description.^{26,27}

However, an investigation of the FCS of such setups is missing. Still, it is needed for an unambiguous identification of the charge transfer processes. In order to proceed as in Sec. II we want to take a different approach compared to the quasiclassical scattering theory by following,⁶⁶⁻⁶⁸ where spin-active scattering is described by the introduction of an additional spin-flip contribution to the Hamiltonian

$$H_{T2} = \sum_{\sigma} \gamma_2 [\Psi_{s\sigma}^+(x=0)\Psi_{f-\sigma}(x=0) + \text{H.c.}]. \quad (8)$$

Adding H_{T2} to the system's Hamiltonian in Eq. (1), we need to introduce a second contribution to Eq. (5) to access the CGF,

$$\chi_{\text{SFa}}(\lambda) = \left\langle T_C \exp \left[-i \int_C dt (T^{\lambda(t)} + T_2^{\lambda(t)}) \right] \right\rangle, \quad (9)$$

where $T_2^{\lambda(t)}$ denotes H_{T2} with the additional substitution $\Psi_{f\sigma}(x=0) \rightarrow \Psi_{f\sigma}(x=0)e^{-i\lambda(t)/2}$. This allows us to calculate the CGF. The actual form of the full CGF is quite complicated due to the presence of Andreev reflection and branch crossing above the gap. We therefore only give a simplified form in Appendix A, Eq. (A1), that allows for a clearer identification of the relevant charge transport processes above and below the gap.

Even in the simplified form we observe a more complicated structure of the CGF compared to Eq. (6) since we need to introduce not only a spin-dependent DOS but also two contact transparencies $\beta_n = \rho_f \rho_0 \gamma^2 \pi^2 / 2$, $\beta_f = \rho_f \rho_0 \gamma_s^2 \pi^2 / 2$ that refer to the normal and spin-flip transparency, respectively. Consequently, the CGF shows single-electron transmission for the different spins as well as spin-flip transmission processes for energies above the gap; see Figs. 1(c) and 1(d). For energies below the gap we identify two types of Andreev reflection: spin-symmetric Andreev reflection (AR) and anomalous⁶⁹ or spin-flip Andreev reflection (SAR), the latter involving a spin-flip process during the Andreev reflection; see Figs. 1(a) and 1(b). We therefore have obtained the FCS of all charge transfer processes that have also been identified in the quasiclassical Green's function calculation.²² The only difference is the description of spin-active scattering. Grein *et al.* use the spin-mixing angle θ_s as the phenomenological parameter, whereas we use a second tunneling transparency to account for spin flips. Both descriptions are related since both give rise to Andreev bound states characterized by $T_A(\epsilon_{\pm}) = 1$ from which one can calculate θ_s via $\epsilon_{\pm} = \pm \Delta \cos(\theta_s/2)$.²²

The SAR implies a spin-flip to convert a singlet Cooper pair from the SC to a triplet pair in the FM, whereas AR just transfers singlets to the FM. Spin-active scattering therefore

gives rise to triplet correlations in the FM,^{70,71} which are responsible for a long-range proximity effect also in FMs.

Apart from the quasiclassical Green's function formalism²² and the approach presented here, a third theoretical treatment has been frequently used for the analysis of SFQPCs: the extended BTK model.¹ In this model, the ratio of γ_2 and γ is fixed for every possible value of γ . This model has been very successful for certain setups¹ but fails for others.^{22,27,64} The problems in fitting conductance spectra with the extended BTK model have also been addressed before by explicit comparison to experimental data.⁵

Here we show that our model (as the quasiclassical Green's function formalism) reproduces the experimental data from Ref. 1 for a finite spin-flip amplitude. As the data can also be fitted by the extended BTK model this shows that one can reproduce its results.

We calculate the differential conductance from the current given by the first derivative of the CGF with respect to the counting field $I_{\text{SFa}} = -i/\tau \partial \ln \chi_{\text{SFa}}(\lambda)/\partial \lambda|_{\lambda=0}$. We compare the differential conductance dI_{SFa}/dV to the experimental data for Al/Co contacts.¹ The result is shown in Fig. 2.

We obtain perfect agreement for a reasonable Dynes parameter (meaning much smaller than the gap), which again signifies the importance of spin-active scattering for strongly polarized FMs as cobalt. The result incorporating spin-active scattering may also be compared to the best possible fit without spin-active scattering (see Fig. 2). We see that a consistent explanation of the experimental data heavily relies on the inclusion of a complete description of the interface region. The possibility of SAR opens a new transport channel below

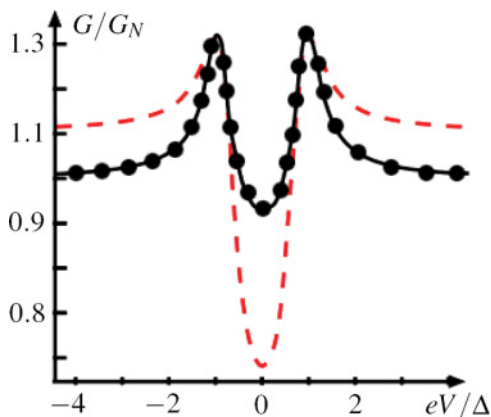


FIG. 2. (Color online) Experimental data for the differential conductance as a function of V through an SFQPC taken from Ref. 1 (black solid curve). The data has been normalised with respect to the normal state conductance G_N . Additionally, the experimental data has been scaled with the fit parameter Δ from our model with spin-active scattering. We plot the prediction by this model (black dots curve) for $T = 0.1\Delta_0$, $\beta_n = 0.095$, $\beta_f = 0.065$, $P = 0.38$ and a broadening of the BCS DOS described by $\Gamma_D = 0.09\Delta_0$. One observes the characteristic double peak structure at the superconducting gap. We also compare this result to the best possible fit without spin-active scattering using $T = 0.13\tilde{\Delta}_0$, $\beta_n = 0.13$, $\beta_f = 0$, $P = 0.38$, $\Gamma_D = 0.09\tilde{\Delta}_0$ and $\tilde{\Delta}_0 = 0.75\Delta$ (dashed red curve). $\tilde{\Delta}_0$ is the fit parameter for the gap in the model without spin-active scattering.

the gap that leads to an increased conductance for $V < \Delta_0$. Indeed, the contribution by SAR is sizable since the ratio of SAR versus AR is determined by the ratio of β_f and β_n being of the order of 0.7. This is in accordance with other studies of different point contacts.^{22,72}

To account for the scaling of the experimental data we express our fit parameter Δ_0 in terms of the BTK fit parameter Δ . Both fitting parameters are identical only when we use the CGF including spin-active scattering. Also, the experiments on Al/Co contacts use samples with several transmission channels. The theoretical investigation in Ref. 1, however, revealed that the samples may be effectively described by a single-channel model using an effective transmission coefficient.

The FCS allows for the calculation of the noise power given by the second derivative of the CGF $S_{\text{SFa}} = -1/\tau \partial^2 \ln \chi_{\text{SFa}}(\lambda)/\partial \lambda^2|_{\lambda=0}$. In the case of small interface transparency we find the smooth transition from Andreev reflection noise (corresponding to a Fano factor of 2) below the gap to single electron noise above the gap (corresponding to a Fano factor of 1), since these represent the only dominant charge transfer processes in these regimes.⁷³⁻⁷⁶ This picture is very similar to the one obtained for NSQPCs since the charge transfer processes in both systems are the same.

IV. FERROMAGNET-QUANTUM DOT-SUPERCONDUCTOR DEVICE IN THE KONDO LIMIT

In this Section we study the generalization of our results to QD geometries. Even in the simplest case this requires the solution of the Anderson impurity model with ferromagnetic leads. However, for the here analyzed F-QD-S experiment¹⁸ the situation is such that we are clearly in the Kondo regime for an odd number of electrons on the QD.⁷⁷ In this case, we observe the many-body spin 1/2 Kondo resonance⁷⁸ for temperatures below the Kondo temperature T_K . Depending on the ratio T_K/Δ , two scenarios may occur: For small T_K/Δ the Kondo resonance is weakly coupled to the SC due to the absence of mobile electrons at the Fermi edge. For large T_K/Δ the Kondo resonance couples to the quasiparticles in the SC. This picture is confirmed both theoretically and experimentally: Theoretically, the dot spectral density for a normal-QD-SC system has been analyzed in Ref. 20, showing a crossover from a double peak around the Fermi energy to a single Kondo resonance upon increasing onsite interaction U . It was also found that the double peak is due to the SC proximity effect. Experimentally, for two superconducting drains and $T_K \lesssim \Delta_0$, the Kondo effect is suppressed,⁷⁹ whereas for a SC hybrid junction and $T_K \lesssim \Delta_0$ one observes a strong suppression of the effective hybridization between the dot and the superconducting drain.¹⁹ This picture allows for an *ad hoc* but practicable approach to our more complicated setup, which is supported by comparison to the experimental data. Since we are clearly in the Kondo regime, we may assume to be at the strong-coupling fixed point where a perfectly transmitting channel opens up and the transport properties of the Kondo effect can be described as the ones of a pure resonant level system as far as the electronic transport is concerned.⁸⁰ Additionally, we want to assume to have T_K/Δ small. Our

approach therefore will be limited to the constellation of parameters $T_K < \Delta < U$. In this situation we will encounter a weak coupling of the SC to the Kondo resonance and we may use an effective description of the Kondo resonance as a resonant level weakly coupled to the SC on top of a (small) background conductance⁸¹ in order to describe the experiment. The background conductance describes in a first approximation the DOS outside the Kondo peak, e.g., the Hubbard subbands at $\pm U/2$. An effective model for the normal-QD-SC case was analyzed in Refs. 19 and 39 where the resulting transmission coefficients for the Kondo resonance are just the product of the transmission coefficient for the tunneling case with the DOS of a resonant level. This simple model has been verified both theoretically and experimentally: We compared the conductance features of our approach to the theoretical calculation in Ref. 20 and observed good agreement in the considered range of parameters. In Ref. 39 the results of this ansatz were compared to the experimental data from Ref. 19. Such procedure may also be applied to the FM-case as one can see from the calculation for the resonant level.²⁸

Additionally, we have to take into account that the Kondo resonance splits into a doublet in a magnetic field according to the Zeeman energy and is also strongly affected by the exchange field of the FM. Using Haldane's scaling method for a flat band structure with spin-dependent tunneling rates and including a finite Stoner splitting of the leads an analytical formula for the energy splitting of the spin- \uparrow and spin- \downarrow bands is found^{34,35} to be⁸²

$$\delta_{\text{split}} = g\mu_B B + \Delta_s + \frac{P\Gamma_K}{\pi} \ln\left(\frac{|\Delta_d|}{|U + \Delta_d|}\right), \quad (10)$$

where Γ_K is the hybridization of the ferromagnetic drain with the Kondo dot and Δ_d is the position of the energy level of the QD. $g\mu_B B$ is the Zeeman splitting with Bohr's magneton μ_B and the gyromagnetic ratio g . Δ_s is a Stoner splitting-induced shift.⁸³ Equation (10) is supported by a refined analysis based on numerical renormalization group calculations.^{34,35} The two spin bands refer to two Kondo singlets which can be described by an effective DOS with a Lorentzian shape given by

$$\rho_{K\sigma}(\omega) = \frac{\Gamma_K^2}{(\omega - eV + \sigma\delta_{\text{split}})^2 + \Gamma_K^2}. \quad (11)$$

This form assumes that we have two spin split Kondo singlets that both lead to perfectly transmitting channels and are associated with the separate spin species. In the case of a FM lead spin symmetry is broken so the Kondo screening clouds associated to the two Kondo singlets differ and thus so do the couplings of the SC to the Kondo peaks. In a first approximation they are given by the tunnel couplings in the SFQPC. The transmission coefficients for the case of a F-QD-S device thus can be deduced from the transmission coefficients for the SFQPC and the relevant effective DOS,

$$T_{eK\sigma}(\omega) = T_{e\sigma}(\omega)\rho_{K\sigma}(\omega),$$

$$T_{AK}(\omega) = T_A(\omega)\rho_{K\sigma}(\omega)\rho_{K-\sigma}(-\omega).$$

Additionally, we have to include the background conductance, which may be done using the standard Levitov-Lesovik

formula⁸⁴

$$\ln \chi_g(\lambda, \tau) = 2\tau \int \frac{d\omega}{2\pi} \ln\{1 + T_g[(e^{i\lambda} - 1)n_{f+}(1 - n_s) + (e^{-i\lambda} - 1)n_s(1 - n_{f+})]\},$$

with an energy-independent transmission coefficient T_g for electron transfer. The CGF for the F-QD-S junction is given by

$$\ln \chi_{\text{F-QD-S}} = \ln \chi_{\text{res}} + \ln \chi_g, \quad (12)$$

where χ_{res} can be derived from χ_{SF} by replacing $T_{e\sigma}$ by $T_{eK\sigma}$ and T_A by T_{AK} . In principle, one would also have to take into account branch crossing and Andreev reflection above the gap. However, we checked that in the limit of $\beta_n \ll 1$, which represents the typical experimental case of small hybridization of the SC with the Kondo resonance, the corresponding transmission coefficients T_{A2} and T_{BC} may safely be neglected since their contribution is marginal.

We compare our results to the experimental data obtained in Ref. 18. In the experimental setup a ferromagnetic drain is formed by a Ni/Co/Pd trilayer and a Ti/Al bilayer is used as a superconducting drain. A QD forms in an InAs nanowire segment contacted by the FM and the SC. In agreement with previous experiments^{85,86} the QD is perfectly controllable by a backgate voltage. The choice of InAs is essential as its g -factor in a wire geometry is comparable to the (rather big) bulk value.^{85,87}

Within this experiment, the observed splitting of the Kondo resonance according to Eq. (10) has been verified. To test our model for the transport characteristics, we choose a charge state that exhibits a clear signature of ferromagnetic correlations, i.e., the Kondo resonance has a finite and roughly constant splitting at $B = 0T$. In this case δ_{split} is constant. We calculate the differential conductance and show the comparison of theory and experiment in Fig. 3.

We observe acceptable agreement in the voltage range considered here. In particular, we see that our model correctly describes the asymmetry of the two Kondo conductance peaks that may be traced back to the different DOS for the two spin

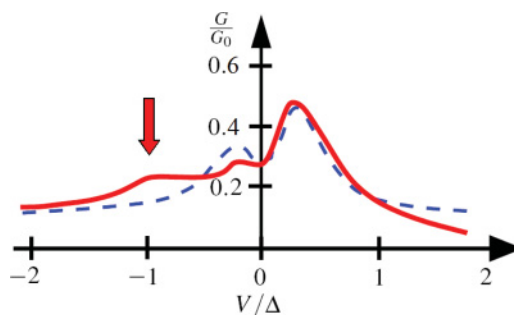


FIG. 3. (Color online) Theoretical differential differential conductance (dashed curve) through the F-QD-S junction for $T = 0.13\Delta$, $\beta_n = 0.036$, $\Gamma_K = 0.29\Delta$, $P = 0.46$, $\delta_{\text{split}} = 0.16\Delta$, $T_g = 0.035$, and $\Delta_0 = 0.23\Delta$. One observes the characteristic double peak structure,¹⁹ however, now with the asymmetry related to the Kondo peak splitting. We compare our prediction to the experimental data (solid curve) taken from Ref. 18 at the background voltage $V_{\text{BG}} = 1.28$ V and $\Delta = 0.14$ meV. The red arrow indicates the bare SC gap observable in the experimental data.

species. Concerning the fitting parameters of our model, we find that we observe no quasiparticle-lifetime broadening of the SC DOS and the value for the polarization is typical for cobalt-based junctions.¹ The width of the Kondo resonance has a typical size also found in other experimental setups and theoretical treatments.¹⁹ From the fit we find $\Gamma_K \lesssim \Delta$, and, thus, $T_K \lesssim \Delta$, so we access the interesting Kondo regime where the Kondo effect and superconductivity are concurring phenomena. We should also add that the value δ_{split} allows us to calculate the g -factor for the considered charge state considered since the critical magnetic B_c field is related to the exchange field splitting via $g\mu_B B_c = 2\delta_{\text{split}}$. B_c has been measured in the experiment to be 64 mT. The corresponding g -factor would be 12, which is in perfect accordance with previous experimental studies of InAs nanowires.⁸⁵ The small value $\Delta_0 = 0.23\Delta$ signifies that the Kondo resonance couples to quasiparticle states within the superconducting gap, which can be ascribed to the granularity of the metallic contacts⁸⁸ and/or a nonzero DOS in the nanowire sections adjacent to the QD.⁸⁹ The most important source of deviations from our model is that we neglected a possible energy dependence of the background DOS and the superconducting correlations on the quantum dot. Indeed, due to the latter assumption in our model, we see no bare superconducting gap at $V = -\Delta$ (see red arrow in Fig. 3).

The result reveals two basic facets of F-QD-S junctions. The first observation is that the background DOS (given by the transmission coefficient T_g) is very small. The second intriguing feature is the absence of spin-active scattering. In our model, we did not include a spin-active tunneling term as in Eq. (8). Such a term would couple the tunnel transmission for one spin species to the Kondo singlet for the opposite spin, which would reduce the asymmetry in the peaks. Additionally, SAR processes would have to be taken into account that couple only to one Kondo singlet and would, therefore, lead to a pronounced subgap feature. A subgap feature of this type will be discussed in Sec. VI, where we show its relevance for a QD in the even state. Both characteristics are not observed and the value for the polarization ($P = 0.46$) that reflects the asymmetry of the peaks is in perfect accordance with previous experimental studies of point contacts. The absence of spin-active scattering even in the presence of a strongly polarized FM is related to the strong asymmetry of the couplings between the dot and the FM or the SC, respectively. The Kondo effect is mainly due to hybridized FM bulk states so specifics of the interface or the SC are hardly seen. This also explains why the theory in Ref. 35 applies also for the case of a F-QD-S junction even though it has been derived for a QD coupled to two ferromagnetic leads.

The CGF in Eq. (12) also includes the possibility of Andreev reflection. Due to the low tunneling coupling of the SC to the QD it is strongly suppressed. However, in Ref. 39 it was found that the presence of Andreev reflection for a normal-QD-SC junction can be decided by a noise measurement. In the case of a F-QD-S junction, the Fano factor does not change considerably since Andreev reflections are suppressed not only by the small tunneling coupling but also by the Kondo peak splitting. Therefore, higher-order cumulants are necessary to decide the presence of Andreev reflections in these devices.

It is remarkable that the asymmetry and splitting deduced from the model can be explained with a reasonable choice of the g -factor of InAs and the polarization of cobalt. Additionally, the asymmetry of the Kondo conductance peaks can be traced back to the different spin species, which we want to exploit in the next section.

V. SPIN MEASUREMENT

In this Section we show that the F-QD-S device can be used for spin measurement. We take advantage of the above observation that Andreev reflection can be neglected as far as conductance is concerned and obtain the FCS for the separate spins as

$$\ln \chi_{\text{F-QD-S}\sigma} = \ln \chi_{\text{res}\sigma} + \ln \chi_{b\sigma}. \quad (13)$$

The $\ln \chi_{\text{res}\sigma}$ is obtained from χ_{res} by setting $T_{eK-\sigma} = 0$ and $T_{AK} = 0$. Likewise, $\ln \chi_{b\sigma}$ is obtained from $\ln \chi_b$ by setting $\ln \chi_{b\sigma} = 1/2 \ln \chi_b$ since the background is assumed to be spin symmetric. We now may calculate the conductance G_σ for the two spin species as usual from the respective FCS. This allows us to derive the quality factor for spin filtering in our device along the lines of Ref. 90

$$q = \left| \frac{G_\uparrow - G_\downarrow}{G_\uparrow + G_\downarrow} \right|. \quad (14)$$

The result is given in Fig. 4 using the parameters $T = 0.13\Delta$, $\beta_n = 0.036$, $\Gamma_K = 0.29\Delta$, $P = 0.46$, $\delta_{\text{split}} = 0.16\Delta$, $T_g = 0.035$, and $\Delta_0 = 0.23\Delta$ as determined from the experimental data above. The quality factor reaches about 70% for voltages around 0.3Δ , where the conductance for the majority spin (spin- \uparrow) is dominant. For $V/\Delta \approx -0.15$ the minority spin component (spin- \downarrow) is dominant. For $V/\Delta \approx -0.3$ both spin directions have roughly the same transmission probability (q goes to zero) and for even lower voltages the spin- \uparrow component again takes over, which causes another dip in the q plot in Fig. 4. A possible quality factor of 70% is much better than with a simple ferromagnetic tunneling contact as there one could only reach a quality factor equal to the polarization P , meaning

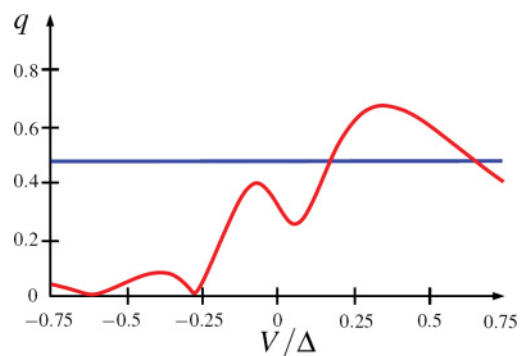


FIG. 4. (Color online) Calculation of the quality factor in Eq. (14) for spin filtering with the same experimental parameters as used in the fit in Fig. 3. We have neglected Andreev reflections since we have shown that they do not considerably change the conductance properties. The quality factor reaches about 70%, taking into account the effect of finite temperature in the experiment. The blue line indicates the quality factor $q = P$ of a simple tunneling junction to a FM with equal polarization $P = 0.46$.

$\approx 46\%$. We should emphasize that in comparison to the QD spin valve considered in Ref. 91 our geometry is simpler since we do not have to work with three leads. Moreover, we do not have to rely on interaction effects in quantum wires^{92,93} or the antiresonance in double QDs.⁹⁰

The behavior shown in Fig. 4 can be explained by the interplay of the two Kondo resonance peaks that correspond to the separate spin components of the current. For $V/\Delta \approx 0.3$ electronic transport proceeds mainly through the Kondo singlet for spin- \uparrow , which explains the large spin polarization. For negative bias the spin- \downarrow component becomes dominant. The quality factor, however, does not reach the same height as for spin- \uparrow due to the different density of states for the two spin species in the ferromagnet. For large bias, electronic transport proceeds mainly through the spin-symmetric background so the quality factor of spin-filtering goes to zero. Therefore, the capability for spin measurement is a combined effect of the asymmetric density of states in the ferromagnet and the splitting of the Kondo resonances by the exchange field δ_{split} .

Depending on the voltage bias a specific spin direction may be tuned to contribute to charge transfer due to the splitting of the Kondo peak. Additionally, the Kondo peak defines an almost perfect interface as it aligns the interface spin with the bulk FM. This makes the F-QD-S setup an ideal spin filter. This is of special importance in the case of Cooper pair splitters⁹⁴⁻⁹⁶ where the final proof of entanglement heavily relies on an effective spin measurement.^{28,29,97,98}

VI. FERROMAGNET-QUANTUM DOT-SUPERCONDUCTOR DEVICE IN THE EVEN STATE

Finally, we want to investigate the even state of the QD. We did not need to incorporate spin-active scattering in the Kondo regime but with an even population of the QD the Kondo resonance disappears. The absence of the collective state at the Fermi level of the FM allows for the possibility of interface effects. Indeed, we find a pronounced mini-gap feature for an even charge state¹⁸ which may be explained by a scenario based on spin-active scattering as in the case of a QPC considered in Sec. III (see Fig. 5). We consider an effective model for an interacting QD in an even charge state. Since the level spacing of the dot ($\Delta E \approx 0.4$ meV) is significantly larger than the mini-gap energy, we focus on a single orbital level in the discussion. The Hamiltonian for a simple resonant level coupled to a FM and a SC with spin-active scattering but

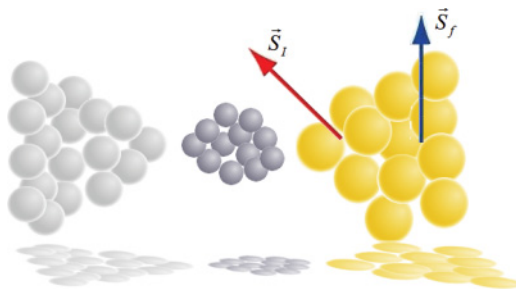


FIG. 5. (Color online) The two magnetic moments of the bulk FM \vec{S}_f and the interface \vec{S}_i may be misaligned. This leads to spin-active scattering also in QD junctions.

still without the Coulomb interaction and the exchange field already has many parts given by

$$H = H_f + H_s + H_d + H_{TRs} + H_{TRf} + H_{TR2}. \quad (15)$$

H_f and H_s again describe the FM and the SC; see Eqs. (2) and (3). The QD, however, has to be taken into account explicitly now and is given by a resonant level at energy δ_σ ,

$$H_d = \sum_{\sigma} \delta_{\sigma} \tilde{d}_{\sigma}^{\dagger} \tilde{d}_{\sigma}, \quad (16)$$

where the \tilde{d}_{σ} operator is the annihilator of the electron state on the dot and $\delta_{\sigma} = \delta + \sigma \Delta \epsilon / 2$ is σ dependent because of the exchange field $\Delta \epsilon$ induced by the bulk FM. Equation (16) is a good starting point since no collective state of the lead and the QD develops in the even charge state, which is characterized by $\delta = 0$. We, first, solve the resonant level case and then show how to implement the exchange field and Coulomb interaction in our effective model.

Because of the interface effects the magnetization axis on the ferromagnetic tunneling junction is rotated with respect to that in the bulk as illustrated in Fig. 5. This is the essence of the spin-active scattering effect,¹⁰⁰ see e.g., Ref. 22. In order to model that we include a spin-flip tunneling between the dot and the ferromagnet, the tunneling part of the Hamiltonian is given by

$$H_{TR} = \sum_{\sigma} \tilde{\gamma}_s (\tilde{d}_{\sigma}^{\dagger} \Psi_{s\sigma} + \text{H.c.}) + \sum_{\sigma} \tilde{\gamma}_f (\tilde{d}_{\sigma}^{\dagger} \Psi_{f\sigma} + \text{H.c.}) + \sum_{\sigma} \tilde{\gamma}_{f2} (\tilde{d}_{\sigma}^{\dagger} \Psi_{f-\sigma} + \text{H.c.}). \quad (17)$$

For computational reasons it is inconvenient to work with the spin-flip tunneling on the dot-FM interface. We choose to rotate the dot fields via

$$d_{\sigma} = \frac{\gamma_f \tilde{d}_{\sigma} + \gamma_{f2} \tilde{d}_{-\sigma}}{\sqrt{\gamma_f^2 + \gamma_{f2}^2}}, \quad (18)$$

Rewriting Eq. (17) in the new basis we obtain

$$H_{TR\alpha} = \sum_{\sigma} \gamma_{\alpha} (d_{\sigma}^{\dagger} \Psi_{\alpha\sigma} + \text{H.c.}), \quad \alpha = s, f$$

$$H_{TR2} = \sum_{\sigma} \gamma_{s2} (d_{\sigma}^{\dagger} \Psi_{s-\sigma} + \text{H.c.}),$$

where

$$\gamma_s = \frac{\gamma_s \gamma_f}{\sqrt{\gamma_f^2 + \gamma_{f2}^2}}, \quad \gamma_{s2} = \frac{\gamma_s \gamma_{f2}}{\sqrt{\gamma_f^2 + \gamma_{f2}^2}}.$$

So the spin-flip tunneling is effectively shifted to the dot-SC interface. Obviously, the above transformation does not change the dot Hamiltonian (16).

First, we consider the QD without the exchange field ($\delta_{\sigma} = 0$) and onsite Coulomb interaction. In order to access the CGF, we need to introduce two counting fields for the separate leads. This means that now we have three contributions compared to Eq. (9)

$$\chi_{\text{RSFa}}(\lambda) = \left\langle T_{\mathcal{C}} \exp \left[-i \int_{\mathcal{C}} (T_R^{\lambda(t)} + T_{R2}^{\lambda(t)} + T_{R3}^{\lambda(t)}) dt \right] \right\rangle, \quad (19)$$

where $T_R^{\lambda(t)}$ and $T_{R2}^{\lambda(t)}$ represent H_{TRs} and H_{TR2} with the substitution $\Psi_{s\sigma}(x=0) \rightarrow \Psi_{s\sigma}(x=0)e^{-i\lambda_s(t)/2}$ and $T_{R3}^{\lambda(t)}$ can be obtained from H_{TRf} with the substitution $\Psi_{f\sigma}(x=0) \rightarrow \Psi_{f\sigma}(x=0)e^{-i\lambda_f(t)/2}$. Using the Hamiltonian approach as before we arrive at the CGF given in Appendix B, Eq. (B1).

The emerging formula is formally identical to the result for the SFQPC with spin-active scattering in Eq. (A1) but with energy-dependent transmission coefficients. Above the gap we observe single electron transmission and spin-flip transmission while below the gap we obtain AR and SAR. The spin-active scattering leads to triplet correlations in the ferromagnet. This kind of proximity phenomenon is mediated by the QD instead of a tunneling contact as in Sec. III. The new feature in our setup is that the triplet correlations feel the exchange field of the bare ferromagnet which allows for a qualitatively new mini-gap feature.

$$\ln \chi_{es}(\lambda, \tau) = 2\tau \int \frac{d\omega}{2\pi} \left(\ln \left\{ 1 + \sum_{\sigma} T_{es\sigma} [n_{f+}(1-n_s)(e^{i\lambda} - 1) + n_s(1-n_{f+})(e^{-i\lambda} - 1)] \right\} \theta \left(\frac{|\omega| - \Delta_0}{\Delta_0} \right) + \frac{1}{2} \ln \left\{ 1 + \sum_{\sigma} T_{esAT\sigma} [n_{f+}(1-n_{f-})(e^{2i\lambda} - 1) + n_{f-}(1-n_{f+})(e^{-2i\lambda} - 1)] \right\} \theta \left(\frac{\Delta_0 - |\omega|}{\Delta_0} \right) \right), \quad (20)$$

where the transmission coefficients are

$$T_{es\sigma} = \frac{4\Gamma_{f\sigma}\Gamma_{s11}}{(\Gamma_{f\sigma} + \Gamma_{s11})^2 + (\omega - \delta_{\sigma})^2},$$

$$T_{esAT\sigma} = \frac{4\Gamma_{s23}^2\Gamma_{f\sigma}}{(\omega - \delta_{\sigma})^2(\omega - \delta_{\sigma} + U)^2 + (\Gamma_{s23}^2 + \Gamma_{f\sigma}^2)^2 + \Gamma_{s23}^2(\omega - \delta_{\sigma})(\omega - \delta_{\sigma} + U) + \Gamma_{f\sigma}^2(\omega - \delta_{\sigma})(\omega - \delta_{\sigma} + U)},$$

We have used the abbreviations $\Gamma_{f\sigma} = \Gamma_f(1 + \sigma P)$, $\Gamma_{s11} = \Gamma_s|\omega|/\sqrt{|\omega^2 - \Delta_0^2|}$, and $\Gamma_{s23} = 2\sqrt{\Gamma_s\Gamma_{s2}\Delta_0}/\sqrt{|\Delta_0^2 - \omega^2|}$ that involve $\Gamma_f = \pi\rho_f\gamma_f^2/2$, $\Gamma_s = \pi\rho_s\gamma_s^2/2$, and $\Gamma_{s2} = \pi\rho_s\gamma_{s2}^2/2$. We compare the results of our model described above to the experimental data in Fig. 6. We see that spin-active scattering in the presence of Coulomb interaction may lead to a significant mini-gap feature with a width of $\approx \Delta$ and

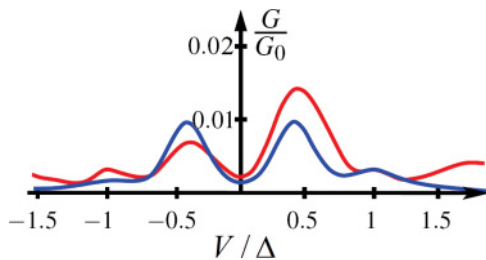


FIG. 6. (Color online) The conductance for a single channel contact with spin-active scattering is shown as a function of the voltage. The theoretical prediction by our model is the blue curve and the red curve refers to the experimental data taken from Ref. 18 at a background voltage $V_{BG} = 11.175$ V. The theoretical fit has been done using the parameters $\Gamma_f = 0.01\Delta$, $\Gamma_s = 0.005\Delta$, $\Gamma_{s2} = 0.015\Delta$, $P = 0.46$, $T = 0.1\Delta$, and $U = 2\Delta$, and the gap Δ_0 has been chosen such that the peaks are at the correct position $\Delta_0 = 0.9\Delta$. Furthermore, we can infer $\delta_{\uparrow} = 0.4\Delta$.

Let us now turn to the situation of an interacting QD with a level splitting given by finite δ_{σ} . The inclusion of the Coulomb interaction is done in the same way as in Ref. 99 for a Josephson junction: for the Andreev reflection transmission coefficients the second spin level has to account for the local exchange field U . This procedure is formally equivalent to a mean-field solution, including Coulomb interaction. The later analysis of the experimental data shows $\Delta\epsilon \lesssim \Delta_0$, Δ_0 being much larger than the tunnel rates of the dot to the FM/SC lead. Using this assumption the result may be greatly simplified: for energies above the gap, spin-flip transmissions (and, thus, H_{TR2}) can be neglected since they involve both spin species. Below the gap AR involves both spin species and therefore can be neglected as well. The CGF for the resulting effective model for a QD in the even state is given by

conductance peaks even higher than the ones associated to the SC gap. The effective model correctly predicts the four-peak structure referring to the SC DOS and the exchange field as one observes in the experiment. It also explains the relation of the mini-gap feature to the ferromagnetic exchange field: SAR occurs via just a single spin level on the QD since it is associated to triplet correlation functions in the bare ferromagnet. In the presence of the ferromagnetic exchange field the two spin levels of the QD split. The exchange field therefore causes a splitting of the two SAR conductance peaks which is directly observable via the new mini-gap feature. This splitting is directly given by $\Delta\epsilon$. We do not get the asymmetry inside the gap. This is due to the shortcomings of our model. An obvious improvement would be a more sophisticated (including correlation effects) calculation in the interaction. Concerning the approximations we made to arrive at Eq. (20), we should note that, indeed, the exchange field $\Delta\epsilon \approx \Delta \gg \Gamma_{f,s,s2}$ so Andreev reflection and single electron spin-flip transmission may be neglected.

Moreover, in the experiment the dependence of the subgap feature on an external magnetic field has been investigated. One observes that the subgap feature does almost not evolve in the magnetic field as long as the superconducting gap is not fully closed. If the gap closes, the mini-gap feature gets strongly suppressed. We can analyze the evolution in magnetic field as well, using the model derived above. We just need to

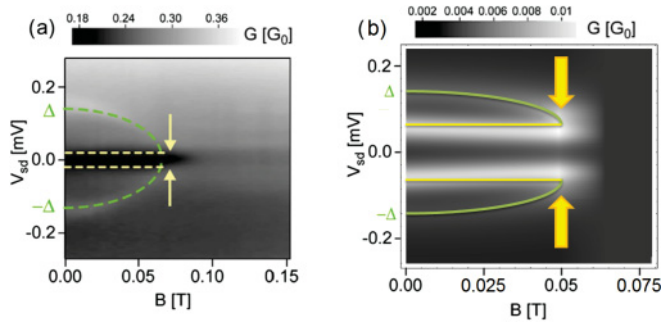


FIG. 7. (Color online) The evolution of the subgap feature in a magnetic field is shown: (a) experimental data for a typical sample different from the one analyzed in Fig. 6 (different charge state). One observes a subgap feature at the energy scale of the exchange field indicated in yellow. The feature is suppressed above the critical field of the SC (indicated by yellow arrows). (b) The conductance as a function of magnetic field given by Eq. (20). We assume $g = 8$ and for a vanishing superconducting gap we assume the conductance to be constant for the voltage range considered here. The critical magnetic field is taken to be $B_c = 64$ mT and $\Delta_0 = 0.14$ meV.

add the term $\sigma g \mu_B B/2$ to the positions of the split levels in Eq. (20), where B refers to the external magnetic field. We use a typical value⁸⁵ of $g = 8$.¹⁰¹ The evolution of the superconducting gap is assumed to be given by

$$\Delta_0(B) = \Delta_0 \sqrt{1 - \left(\frac{B}{B_c}\right)^2},$$

and Δ_0 is substituted in Eq. (20) with $\Delta_0(B)$. For $\Delta_0(B) = 0$ the effective model given by Eq. (20) should no longer be applicable but since we are interested only in the evolution below the gap we assume the conductance for $\Delta_0(B) = 0$ to be constant for the voltage range considered here. We find that our model correctly predicts the qualitative behavior of the mini-gap feature (see Fig. 7). The gap closes, whereas the mini-gap stays in place as long as the gap is not vanishing. This is related to the very large exchange field observed in the experiment. $\delta_\uparrow = 0.4\Delta$ corresponds to a critical magnetic field of the subgap feature of $B_{c,\text{subgap}} = 0.19$ T, which is much larger than the critical magnetic field of the SC. Therefore, we conclude that our model delivers a qualitatively correct description of the underlying physics. According to our explanation, the splitting of the SAR peaks due to the exchange field gives direct evidence for the triplet correlations due to spin-active scattering since normal (spin-symmetric) AR conductance peaks cannot split up in an applied magnetic field. In this way the spin-active scattering can be identified in

simple transport experiments in a way similar to the explicit investigation of Andreev bound states.⁷²

VII. CONCLUSION

In conclusion, we have calculated the FCS for SFQPCs with and without spin-active scattering at the interface. We have demonstrated the necessity to take it into account for a consistent explanation of the current-voltage characteristics. Using these results, we derived an effective description of a F-QD-S contact in the Kondo regime. In this case, the Kondo effect imposes a strong asymmetry between the coupling of the SC and the FM to the QD. Spin-active scattering at the interface is strongly suppressed, making the device an ideal tool for spin measurements in Cooper pair splitters. Spin-active scattering may be “switched on” in an even charge state of the QD. There, as in the case of SFQPCs, it induces triplet correlations that lead to an observable mini-gap feature. Furthermore, our model allows us to reproduce and interpret the evolution of the mini-gap feature in an external magnetic field.

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APPENDIX A: EXPRESSION FOR THE CGF FOR THE SFQPC WITH SPIN-ACTIVE SCATTERING

The CGF for a SC-FM-quantum point contact is quite complicated in full detail and shall not be reported here. To give a clear physical understanding of the processes involved we use an approximation for the noninteracting self-energy due to the superconducting lead that is also used, e.g., in Ref. 102: We treat the noninteracting self-energy of the SC to be real and purely off-diagonal for energies below the superconducting gap and to be diagonal for energies above Δ_0 . The one due to the normal lead is always diagonal. This approximation is valid for $V \ll \Delta_0$ as well as for $V \gg \Delta_0$ so all relevant charge transfer processes are included. For the plots and the comparison to experimental data we use, of course, the full model, which gives a slightly different behavior around $V = \Delta_0$. Using this approximation of the tunneling self-energy, we arrive at

$$\begin{aligned} \ln \chi_{\text{SFa}}(\lambda) = & 2\tau \int \frac{d\omega}{2\pi} [\ln(\{1 + T_{e\sigma}[n_{f+}(1 - n_s)(e^{i\lambda} - 1) + n_s(1 - n_{f+})(e^{-i\lambda} - 1)]\}\{1 + T_{e-\sigma}[n_{f+}(1 - n_s)(e^{i\lambda} - 1) \\ & + n_s(1 - n_{f+})(e^{-i\lambda} - 1)]\} - T_d[n_{f+}(1 - n_s)(e^{i\lambda} - 1) + n_s(1 - n_{f+})(e^{-i\lambda} - 1)]^2 \\ & - T_s[n_{f+}(1 - n_s)(e^{i\lambda} - 1) + n_s(1 - n_{f+})(e^{-i\lambda} - 1)]\theta[|\omega| - \Delta_0]/\Delta_0 \\ & + 1/2 \ln(\{1 + T_A[n_{f+}(1 - n_{f-})(e^{2i\lambda} - 1) + n_{f-}(1 - n_{f+})(e^{-2i\lambda} - 1)]\}^2 \\ & - T_{A2}[n_{f+}(1 - n_{f-})(e^{2i\lambda} - 1) + n_{f-}(1 - n_{f+})(e^{-2i\lambda} - 1)] \\ & + T_{AT}[n_{f+}(1 - n_{f-})(e^{2i\lambda} - 1) + n_{f-}(1 - n_{f+})(e^{-2i\lambda} - 1)]\theta[(\Delta_0 - |\omega|)/\Delta_0]}. \end{aligned} \quad (\text{A1})$$

We define the transmission coefficients to be

$$T_{e\sigma} = \frac{4(\beta_{11\sigma} + \beta_{12\sigma})}{(1 + \beta_{11\uparrow} + \beta_{12\uparrow})(1 + \beta_{11\downarrow} + \beta_{12\downarrow}) - \beta_{13\uparrow}\beta_{13\downarrow}}, \quad T_d = \frac{16\beta_{13\uparrow}\beta_{13\downarrow}}{[(1 + \beta_{11\uparrow} + \beta_{12\uparrow})(1 + \beta_{11\downarrow} + \beta_{12\downarrow}) - \beta_{13\uparrow}\beta_{13\downarrow}]^2},$$

$$T_s = \frac{4[(\beta_{11\uparrow} - \beta_{11\downarrow} + \beta_{12\uparrow} - \beta_{12\downarrow})^2 + \beta_{13\uparrow}\beta_{13\downarrow}]}{[(1 + \beta_{11\uparrow} + \beta_{12\uparrow})(1 + \beta_{11\downarrow} + \beta_{12\downarrow}) - \beta_{13\uparrow}\beta_{13\downarrow}]^2}, \quad T_A = \frac{4[(\beta_{21\downarrow} + \beta_{22\downarrow})(\beta_{21\uparrow} + \beta_{22\uparrow}) - \beta_{23\uparrow}\beta_{23\downarrow}]}{W},$$

$$T_{A2} = \frac{4(\beta_{23\uparrow} + \beta_{23\downarrow})^2(\beta_{21\uparrow} + \beta_{22\uparrow})(\beta_{21\downarrow} + \beta_{22\downarrow})}{W^2}, \quad T_{AT} = \frac{4(\beta_{23\uparrow} + \beta_{23\downarrow})^2[1 + \beta_{23\uparrow}\beta_{23\downarrow}]^2}{W^2},$$

where

$$W = 1 + (\beta_{21\uparrow} + \beta_{22\uparrow})(\beta_{21\downarrow} + \beta_{22\downarrow})[2 + (\beta_{21\uparrow} + \beta_{22\uparrow})(\beta_{21\downarrow} + \beta_{22\downarrow}) - 2(\beta_{21\uparrow} + \beta_{22\uparrow})(\beta_{21\downarrow} + \beta_{22\downarrow})\beta_{23\uparrow}\beta_{23\downarrow} + (1 + \beta_{23\uparrow})^2(1 + \beta_{23\downarrow})^2].$$

In these definitions we used the abbreviations

$$\beta_{11\sigma} = \frac{\beta_n(1 + \sigma P)|\omega|}{\sqrt{\omega^2 - \Delta_0^2}}, \quad \beta_{12\sigma} = \frac{\beta_f(1 + \sigma P)|\omega|}{\sqrt{\omega^2 - \Delta_0^2}}, \quad \beta_{13\sigma} = \frac{2(1 + \sigma P)(\beta_n\beta_f)^{1/2}|\omega|}{\sqrt{\omega^2 - \Delta_0^2}},$$

$$\beta_{21\sigma} = \frac{\beta_n(1 + \sigma P)\Delta_0}{\sqrt{\Delta_0^2 - \omega^2}}, \quad \beta_{22\sigma} = \frac{\beta_f(1 + \sigma P)\Delta_0}{\sqrt{\Delta_0^2 - \omega^2}}, \quad \beta_{23\sigma} = \frac{2(1 + \sigma P)(\beta_n\beta_f)^{1/2}\Delta_0}{\sqrt{\Delta_0^2 - \omega^2}},$$

with $\beta_n = \rho_f \rho_0 s \gamma^2 \pi^2 / 2$ and $\beta_f = \rho_f \rho_0 s \gamma_2^2 \pi^2 / 2$. We observe a more complicated structure of the CGF compared to Eq. (6). Above the gap we observe single-electron transmission for the different spins described by $T_{e\sigma}$. Additionally spin-flip transmission of single electrons must contribute, giving rise to the transmission coefficients T_d and T_s . In the numerator of T_s there are two contributions since one additionally has to keep track of the asymmetric DOS for the different spins. Below the gap we find two types of Andreev reflection: T_A and T_{A2} describe the normal, spin-symmetric Andreev reflection (AR) and T_{AT} describes spin-flip Andreev reflection (SAR).

APPENDIX B: EXPRESSION FOR THE CGF FOR THE F-QD-S JUNCTION WITH SPIN-ACTIVE SCATTERING

We use the same approximation of the self-energy as in Appendix A to simplify the expression. In this approximation the CGF for a F-QD-S junction may be expressed as

$$\ln \chi_{\text{RFSFA}}(\lambda) = 2\tau \int \frac{d\omega}{2\pi} \left[\left(\ln \left\{ 1 + \left[\sum_{\sigma} T_{Re\sigma} \right] [n_{f+}(1 - n_s)(e^{i\lambda} - 1) + n_s(1 - n_{f+})(e^{i\lambda} - 1)] \right. \right. \right. \\ \left. \left. \left. + T_{Rd} [n_{f+}(1 - n_s)(e^{i\lambda} - 1) + n_s(1 - n_{f+})(e^{i\lambda} - 1)]^2 \right. \right. \right. \\ \left. \left. \left. - T_{Rs} [n_{f+}(1 - n_s)(e^{i\lambda} - 1) + n_s(1 - n_{f+})(e^{i\lambda} - 1)] \right\} \theta \left(\frac{|\omega| - \Delta_0}{\Delta_0} \right) \right. \right. \\ \left. \left. + \frac{1}{2} (\ln \{ 1 + 2T_{RA} [(e^{2i\lambda} - 1)n_{f+}(1 - n_{f-}) + (e^{2i\lambda} - 1)n_{f-}(1 - n_{f+})] \right. \right. \right. \\ \left. \left. \left. + T_{RA2} [(e^{2i\lambda} - 1)n_{f+}(1 - n_{f-}) + (e^{2i\lambda} - 1)n_{f-}(1 - n_{f+})]^2 \right. \right. \right. \\ \left. \left. \left. + (T_{RAT} + T_{RA2}) [(e^{2i\lambda} - 1)n_{f+}(1 - n_{f-}) + (e^{2i\lambda} - 1)n_{f-}(1 - n_{f+})] \right\} \right) \theta \left(\frac{\Delta_0 - |\omega|}{\Delta_0} \right), \quad (\text{B1})$$

where we set $\lambda_f - \lambda_s =: \lambda$ and we have the transmission coefficients

$$T_{Re\sigma} = \frac{4\Gamma_{f\sigma}(\Gamma_{s11} + \Gamma_{s12})[(\Gamma_{f-\sigma} + \Gamma_{s11} + \Gamma_{s12})^2 + (\omega - \delta)^2 - \Gamma_{s13}^2]}{\det A_{R10}}, \quad T_{Rd} = \frac{16\Gamma_{f\uparrow}\Gamma_{f\downarrow}[(\Gamma_{s11} + \Gamma_{s12})^2 - \Gamma_{s13}^2]}{\det A_{R10}},$$

$$T_{Rs} = \frac{16\Gamma_{f\uparrow}\Gamma_{f\downarrow}}{\det A_{R10}}, \quad \det A_{R10} = [(\Gamma_{f\uparrow} + \Gamma_{s11} + \Gamma_{s12})^2 + \omega^2 - \Gamma_{s13}^2][(\Gamma_{f\downarrow} + \Gamma_{s11} + \Gamma_{s12})^2 + \omega^2 - \Gamma_{s13}^2]$$

$$+ \Gamma_{s13}^2[(\Gamma_{f\uparrow} - \Gamma_{f\downarrow})^2 + 4\omega^2], \quad T_{RA} = \frac{4\Gamma_{f\uparrow}\Gamma_{f\downarrow}(\Gamma_{s21} + \Gamma_{s22})^2}{\det A_{R20}},$$

$$T_{RA2} = \frac{16\Gamma_{f\uparrow}^2\Gamma_{f\downarrow}^2[(\Gamma_{s21} + \Gamma_{s22})^2 - \Gamma_{s23}^2]^2}{(\det A_{R20})^2}, \quad T_{RAT} = \frac{4\Gamma_{s23}^2[(\Gamma_{f\uparrow}^2 + \Gamma_{f\downarrow}^2)(\Gamma_{s23}^2 - (\Gamma_{s21} + \Gamma_{s22})^2 + \omega^2)^2]}{(\det A_{R20})^2}$$

$$T_{RA2} = \{4\Gamma_{s23}^2\Gamma_{f\uparrow}^2\Gamma_{f\downarrow}^2[\Gamma_{f\uparrow}^2 + \Gamma_{f\downarrow}^2 + 4(\Gamma_{s23}^2 + \omega^2)] - 2\Gamma_{f\uparrow}\Gamma_{f\downarrow}(\Gamma_{s21} + \Gamma_{s22})^2[\Gamma_{f\uparrow}^2 + \Gamma_{f\downarrow}^2 + 4(\Gamma_{s23}^2 + \omega^2)]\} / \{(\det A_{R20})^2\}$$

$$\det A_{R20} = \omega^4 + [(\Gamma_{s21} + \Gamma_{s22})^2 + \Gamma_{f\uparrow}\Gamma_{f\downarrow} - \Gamma_{s23}^2]^2 + 2(\Gamma_{s21} + \Gamma_{s22})^2\omega^2 + \Gamma_{f\uparrow}^2\omega^2 + \Gamma_{f\downarrow}^2\omega^2 + \Gamma_{s23}^2[(\Gamma_{f\uparrow} + \Gamma_{f\downarrow})^2 + 2\omega^2].$$

Again, we have used several abbreviations in these definitions,

$$\Gamma_{f\sigma} = \Gamma_F(1 + \sigma P), \quad \Gamma_{s11} = \frac{\Gamma_s|\omega|}{\sqrt{\omega^2 - \Delta_0^2}}, \quad \Gamma_{s12} = \frac{\Gamma_{s2}|\omega|}{\sqrt{\omega^2 - \Delta_0^2}}, \quad \Gamma_{s13} = \frac{2(\Gamma_s\Gamma_{s2})^{\frac{1}{2}}|\omega|}{\sqrt{\omega^2 - \Delta_0^2}},$$

$$\Gamma_{s21} = \frac{\Gamma_s\Delta_0}{\sqrt{\Delta_0^2 - \omega^2}}, \quad \Gamma_{s22} = \frac{\Gamma_{s2}\Delta_0}{\sqrt{\Delta_0^2 - \omega^2}}, \quad \Gamma_{s23} = \frac{2(\Gamma_s\Gamma_{s2})^{\frac{1}{2}}\Delta_0}{\sqrt{\Delta_0^2 - \omega^2}}$$

with $\Gamma_f = \pi\rho_f\gamma_f^2/2$, $\Gamma_s = \pi\rho_s\gamma_s^2/2$, and $\Gamma_{s2} = \pi\rho_s\gamma_{s2}^2/2$.

The result may be interpreted as the result for the SF tunnel contact with spin-active scattering in Eq. (A1). Above the gap $T_{Re\sigma}$ describes single electron transfer without spin flip and T_{Rd} describes the consecutive transfer of two electrons with different spin (again without spin flip). T_{Rs} refers to spin-flip transmission of single electrons. Below the gap T_{RA} and T_{RA2} describe single Andreev reflection and T_{RA2} describes two consecutive Andreev reflections initiated by electrons with opposite spin. Spin-flip Andreev reflection is given by T_{RAT} .

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